

## UTG20N65-S

## Insulated Gate Bipolar Transistor

## 650V TRENCH GATE FIELD-STOP IGBT

## DESCRIPTION

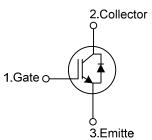
The UTC **UTG20N65-S** is an Trench Field-Stop Insulated Gate Bipolar Transistor. it uses UTC's advanced technology to provide customers with high switching speed, low saturation voltage and low switching loss, etc.

The UTC **UTG20N65-S** is suitable for the resonant or soft switching applications.

## FEATURES

- \* High switching speed
- \* High avalanche ruggedness
- \* Low saturation voltage:  $V_{CE(SAT).Typ.}$ =1.65V @ I<sub>C</sub>=20A, V<sub>GE</sub>=15V (T<sub>C</sub> =25°C)

### SYMBOL

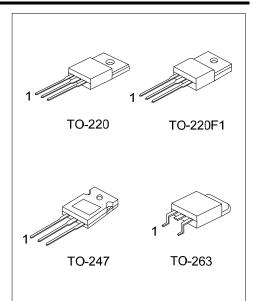


### ORDERING INFORMATION

Ordering Number		Deekere	Pin Assignment			Desking
Lead Free	Halogen Free	Package	1	2	3	Packing
UTG20N65L-TA3-T	UTG20N65G-TA3-T	TO-220	G	С	Е	Tube
UTG20N65L-TF1-T	UTG20N65G-TF1-T	TO-220F1	G	С	Е	Tube
UTG20N65L-T47-T	UTG20N65G-T47-T	TO-247	G	С	Е	Tube
UTG20N65L-TQ2-T	UTG20N65G-TQ2-T	TO-263	G	С	Е	Tube
UTG20N65L-TQ2-R	UTG20N65G-TQ2-R	TO-263	G	С	Е	Tape Reel
Noto: Din Assignment: C: Coto C: Collector E: Emitter						

#### Note: Pin Assignment: G: Gate C: Collector E: Emitter

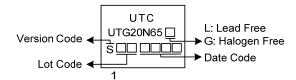
(1)Packing Type	<ul> <li>(1) T: Tube, R: Tape Reel</li> <li>(2) TA3: TO-220, TF1: TO-220F1, T47: TO-247,</li></ul>
(2)Package Type	TQ2: TO-263 <li>(3) G: Halogen Free and Lead Free, L: Lead Free</li>



# UTG20N65-S

## Insulated Gate Bipolar Transistor

## MARKING





## ■ ABSOLUTE MAXIMUM RATINGS

PARAMETER		SYMBOL	RATINGS	UNIT	
Collector-Emitter Voltage		V <sub>CES</sub>	650	V	
Gate-Emitter Voltage		N/	±20	V	
Transient Gate-emitter voltage ( <i>t</i> p < 5 ms)		V <sub>GES</sub>	±25	V	
Continuous Collector Current	T <sub>C</sub> =25°C		40	Α	
	T <sub>c</sub> =100°C	lc	20	А	
Collector Current Pulsed (Note 1)		I <sub>CM</sub>	80	Α	
Diode Forward Current	T <sub>C</sub> =25°C	l <sub>F</sub>	40	Α	
	T <sub>C</sub> =100°C		20	Α	
Short Circuit Withstand Time		tsc		μs	
$V_{GE}$ = 15V, $V_{CC}$ ≤ 200V Allowed number of short circuits < 1000			3		
Time between short circuits: ≥1.0s T <sub>VJ</sub> = 25°C					
Power Dissipation (T <sub>C</sub> =25°C)	TO-220/TO-263		95	W	
	TO-220F1	PD	33	W	
	TO-247	1 [	270	W	
Operating Junction Temperature		TJ	-40 ~ +150	°C	
Storage Temperature Range		T <sub>STG</sub>	-55 ~ +150	°C	

 Notes: 1. Absolute maximum ratings are stress ratings only and functional device operation is not implied. Absolute maximum ratings are those values beyond which the device could be permanently damaged.
 2. Pulse width limited by maximum junction temperature.

#### THERMAL DATA

PARAMETER		SYMBOL	RATINGS	UNIT
Junction to Case	TO-220/TO-263		1.31	°C/W
	TO-220F1	Өлс	3.78	°C/W
	TO-247		0.46	°C/W



## ■ ELECTRICAL CHARACTERISTICS (Tc=25°C, unless otherwise noted)

SYMBOL	TEST CONDITIONS	MIN	TYP	NAAX	
				IMAX	UNIT
BVCES					V
ICES	V <sub>CE</sub> =650V, V <sub>GE</sub> =0V			5	μA
IGES	V <sub>CE</sub> =0V, V <sub>GE</sub> =±20V			±100	nA
V <sub>GE(TH)</sub>	Ic=250µA, Vce=Vge			6.5	V
Vce(sat)	Ic=20A, V <sub>GE</sub> =15V Tc=25°C Tc=125°C		1.65 2.0	2.1	V V
CIES	Vce=25V, Vge=0V, f=1MHz		837		pF
COES			72		pF
CRES			12		pF
QG			53.5		nC
Q <sub>GE</sub>			21		nC
Q <sub>GC</sub>			17.3		nC
t <sub>DON)</sub>			18.5		ns
t <sub>R</sub>			17.6		ns
t <sub>DOFF)</sub>	V <sub>CC</sub> =400V, I <sub>C</sub> =20A, R <sub>G</sub> =5Ω, V <sub>GE</sub> =0~15V, L=1000uH		32		ns
tF			82.4		ns
Eon			0.3		mJ
EOFF			0.55		mJ
CHARACTE	RISTICS				
VF	I <sub>F</sub> =20A		2.1	3.0	V
trr	−I <sub>F</sub> =20A, dl/dt=100A/μS, V <sub>CC</sub> =400V		58.6		ns
Qrr			668		nC
	ICES IGES VGE(TH) VCE(SAT) CIES COES CRES CRES QG QGC tDON) tR tDOFF) tF EON EOFF CHARACTE VF trr	$\begin{array}{c cr} I_{CES} & V_{CE}=650V, V_{GE}=0V \\ \hline I_{GES} & V_{CE}=0V, V_{GE}=\pm 20V \\ \hline \\ \hline V_{GE(TH)} & I_{C}=250\mu A, V_{CE}=V_{GE} \\ \hline \\ \hline \\ V_{CE(SAT)} & I_{C}=20A, V_{GE}=15V \\ \hline \\ $	$\begin{array}{c cr} I_{CES} & V_{CE}=650V, V_{GE}=0V \\ \hline I_{GES} & V_{CE}=0V, V_{GE}=\pm 20V \\ \hline \\ \hline \\ V_{GE(TH)} & I_{C}=250\mu A, V_{CE}=V_{GE} & 4.6 \\ \hline \\ V_{CE(SAT)} & I_{C}=20A, V_{GE}=15V & \hline \\ \hline$	$\begin{array}{c cr} I_{CES} & V_{CE}=650V, V_{GE}=0V \\ \hline I_{GES} & V_{CE}=0V, V_{GE}=\pm 20V \\ \hline \\ \hline V_{GE(TH)} & I_{C}=250\mu A, V_{CE}=V_{GE} \\ \hline \\ V_{CE(SAT)} & I_{C}=20A, V_{GE}=15V \\ \hline \\ I_{C}=20A, V_{GE}=15V \\ \hline \\ \hline \\ \hline \\ C_{IES} \\ \hline \\ C_{CES} \\ \hline \\ C_{CES} \\ \hline \\ V_{CE}=25V, V_{GE}=0V, f=1MHz \\ \hline \\ \hline \\ \hline \\ C_{IES} \\ \hline \\ C_{RES} \\ \hline \\ V_{CE}=520V, I_{C}=20A, V_{GE}=15V \\ \hline \\ \hline \\ C_{IES} \\ \hline \\ C_{IES} \\ \hline \\ \hline \\ C_{IES} \\ \hline \\ C_{IES} \\ \hline \\ \hline \\ C_{IES} \\ \hline \\ V_{CE}=25V, V_{GE}=0V, f=1MHz \\ \hline \\ \hline \\ \hline \\ C_{IES} \\ \hline \\ \hline \\ C_{IES} \\ \hline \\ \hline \\ C_{IES} \\ \hline \\ V_{CE}=25V, V_{GE}=0V, f=1MHz \\ \hline \\ \hline \\ \hline \\ \hline \\ \hline \\ \hline \\ C_{IES} \\ \hline \\ \hline \\ \hline \\ \hline \\ \hline \\ \hline \\ C_{IES} \\ \hline \\ \hline \\ \hline \\ \hline \\ \hline \\ \hline \\ C_{IES} \\ \hline \\ $	$\begin{array}{c crcc} I_{CES} & V_{CE}=650V, V_{GE}=0V & 5 \\ \hline I_{GES} & V_{CE}=0V, V_{GE}=\pm 20V & \pm 100 \\ \hline \\ \hline \\ V_{GE(TH)} & I_{C}=250\mu A, V_{CE}=V_{GE} & 4.6 & 6.5 \\ \hline \\ V_{CE(SAT)} & I_{C}=20A, V_{GE}=15V & \hline \\ \hline \\ I_{C}=125^{\circ}C & 2.0 \\ \hline \\ \hline \\ \hline \\ C_{IES} & \\ C_{CES} & \\ \hline \\ \hline \\ C_{CES} & \\ V_{CE}=25V, V_{GE}=0V, f=1MHz & 72 \\ \hline \\ \hline \\ \hline \\ C_{RES} & \\ \hline \\ \hline \\ \hline \\ \hline \\ \\ C_{RES} & \\ \hline \\ \hline \\ \hline \\ \\ C_{RES} & \\ \hline \\ \hline \\ \\ \hline \\ \\ C_{RES} & \\ \hline \\ \hline \\ \\ \hline \\ \\ C_{RES} & \\ \hline \\ \hline \\ \\ \hline \\ \\ C_{RES} & \\ \hline \\ \hline \\ \\ \hline \\ \\ C_{RES} & \\ \hline \\ \hline \\ \\ \hline \\ \\ C_{RES} & \\ \hline \\ \hline \\ \hline \\ \\ \hline \\ \hline \\ \\ \hline \\ \\ \hline \\ \\ \hline \\ \hline \\ \\ \hline \\ \\ \hline \\ \hline \\ \hline \\ \hline \\ \\ \hline \\ \hline \\ \\ \hline \\ \hline \\ \hline \\ \hline \\ \hline \\ \\ \hline \hline \\ \hline \hline \\ \hline \hline \\ \hline \\ \hline \\ \hline \hline \\ \hline \\ \hline \\ \hline \\ \hline \\ \hline \hline \\ \hline \\ \hline \\ \hline \hline \\ \hline \\ \hline \\ \hline \\ \hline \\ \hline \hline \\ \hline \hline \\ \hline \hline \\ \hline \\ \hline \hline \hline \hline \\ \hline \hline \hline \hline \hline \hline \hline \\ \hline \hline$



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